

### 600V / 15A 6 in one-package

#### ■ Features

- Compact Single in -line package

#### ■ Applications

- Inverter for Motor drive
- AC and DC Servo drive amplifier
- Uninterruptible power supply
- Industrial machines, such as Welding machines



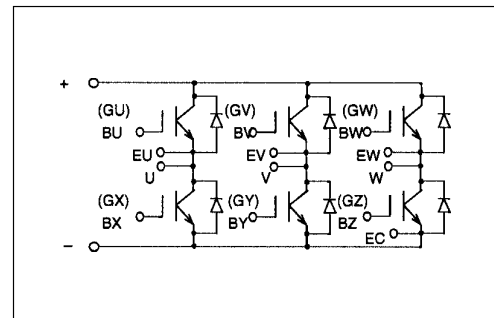
#### ■ Maximum ratings and characteristics

##### ● Absolute maximum ratings (at Tc=25°C unless otherwise specified)

Item	Symbol	Rating	Unit
Collector-Emitter voltage	V <sub>CES</sub>	600	V
Gate-Emitter voltage	V <sub>GES</sub>	±20	V
Collector current	Continuous	I <sub>c</sub>	15 A
	1ms	I <sub>c</sub> pulse	30 A
		-I <sub>c</sub>	15 A
	1ms	-I <sub>c</sub> pulse	30 A
Max. power dissipation	P <sub>c</sub>	60	W
Operating temperature	T <sub>j</sub>	+150	°C
Storage temperature	T <sub>stg</sub>	-40 to +125	°C
Isolation voltage	V <sub>is</sub>	AC 2000 (1min.)	V
Screw torque	Mounting *1	1.7	N·m

\*1 : Recommendable value : 1.3 to 1.7 N·m (M4)

#### ■ Equivalent Circuit Schematic



##### ● Electrical characteristics (at Tj=25°C unless otherwise specified)

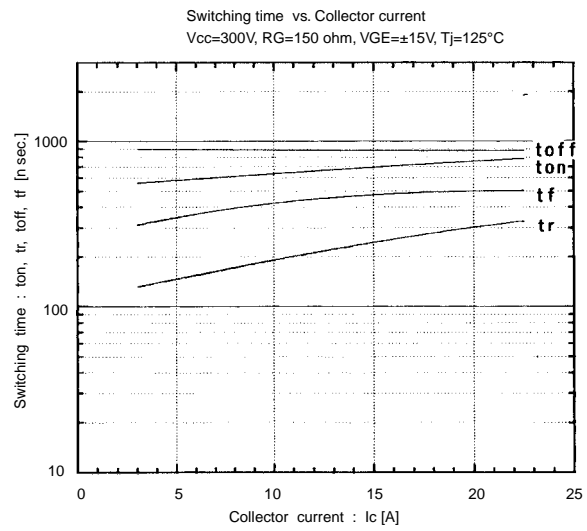
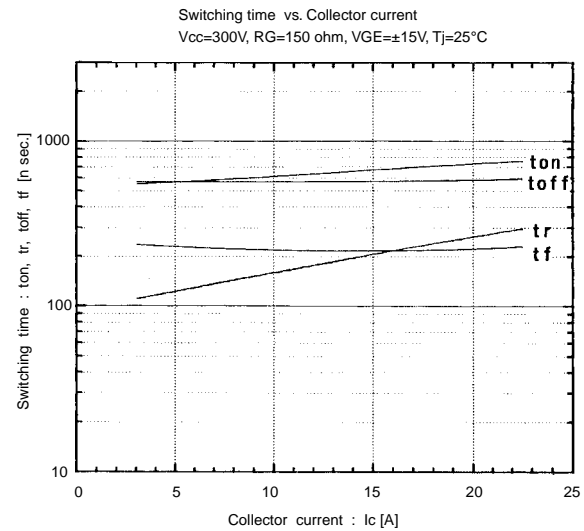
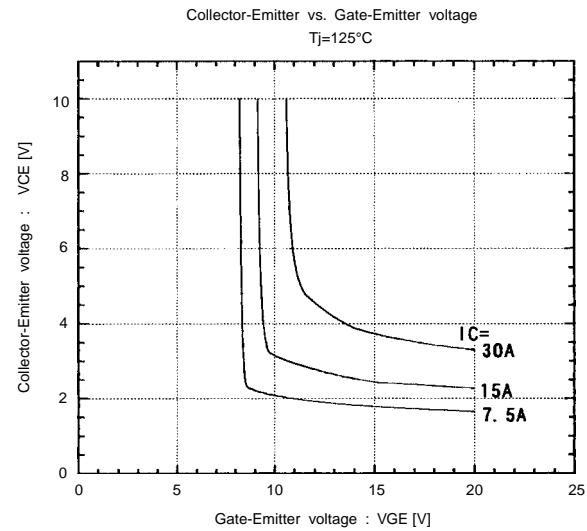
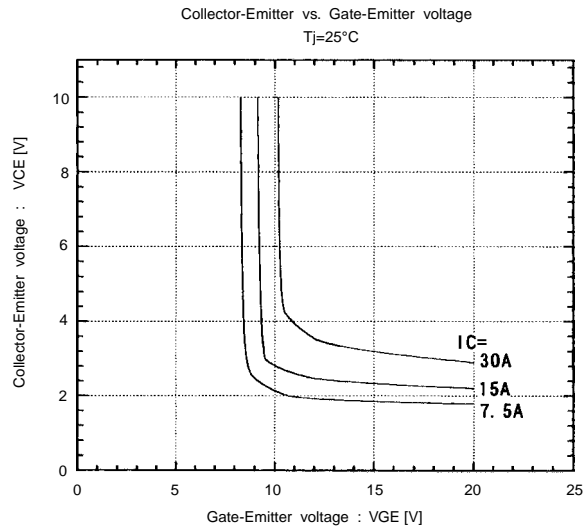
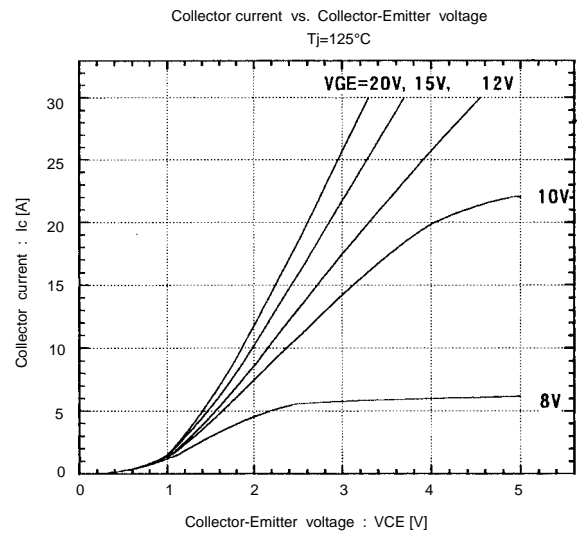
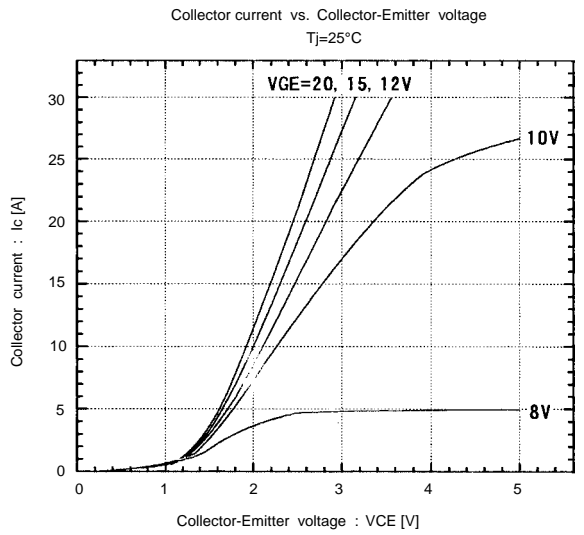
Item	Symbol	Characteristics			Conditions	Unit
		Min.	Typ.	Max.		
Zero gate voltage collector current	I <sub>CEs</sub>	–	–	1.0	V <sub>GE</sub> =0V, V <sub>CES</sub> =600V	mA
Gate-Emitter leakage current	I <sub>GES</sub>	–	–	0.1	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V	µA
Gate-Emitter threshold voltage	V <sub>GE(th)</sub>	5.5	–	8.5	V <sub>CE</sub> =20V, I <sub>c</sub> =15mA	V
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	–	–	2.8	V <sub>GE</sub> =15V, I <sub>c</sub> =15A	V
Input capacitance	C <sub>ies</sub>	–	975	–	V <sub>GE</sub> =0V	pF
Output capacitance	C <sub>oes</sub>	–	225	–	V <sub>CE</sub> =10V	
Reverse transfer capacitance	C <sub>res</sub>	–	54	–	f=1MHz	
Turn-on time	t <sub>on</sub>	–	–	1.2	V <sub>CC</sub> =300V	µs
	t <sub>r</sub>	–	–	1.0	I <sub>c</sub> =15A	
Turn-off time	t <sub>off</sub>	–	–	1.0	V <sub>GE</sub> =±15V	
	t <sub>f</sub>	–	–	0.35	R <sub>G</sub> =150ohm	
Diode forward on voltage	V <sub>F</sub>	–	–	3.0	I <sub>F</sub> =15A, V <sub>GE</sub> =0V	V
Reverse recovery time	t <sub>rr</sub>	–	–	0.3	I <sub>F</sub> =15A, -di/dt=45A/µs, V <sub>GE</sub> =-10V	µs

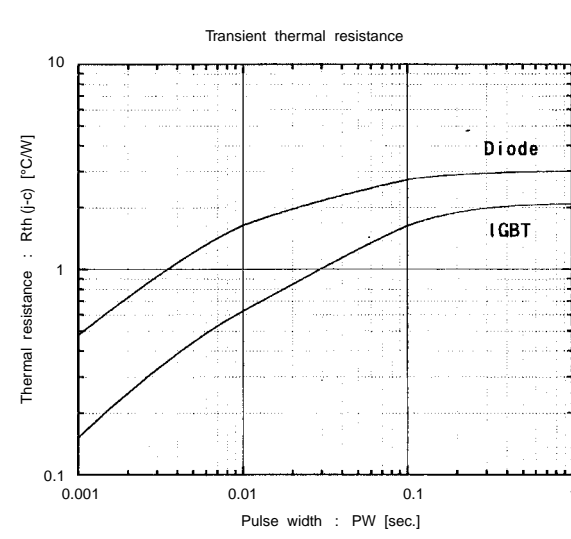
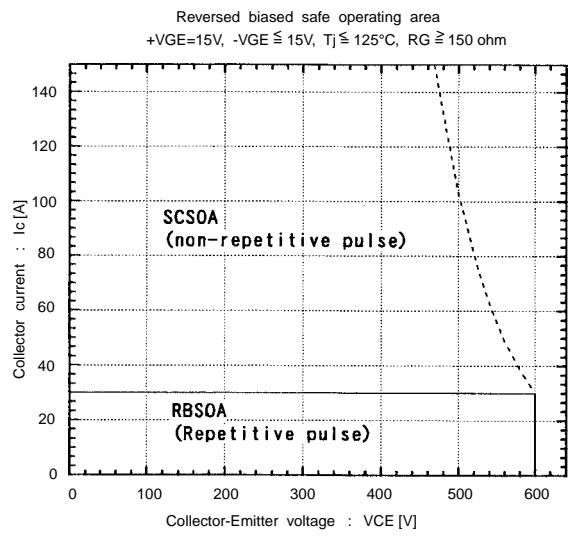
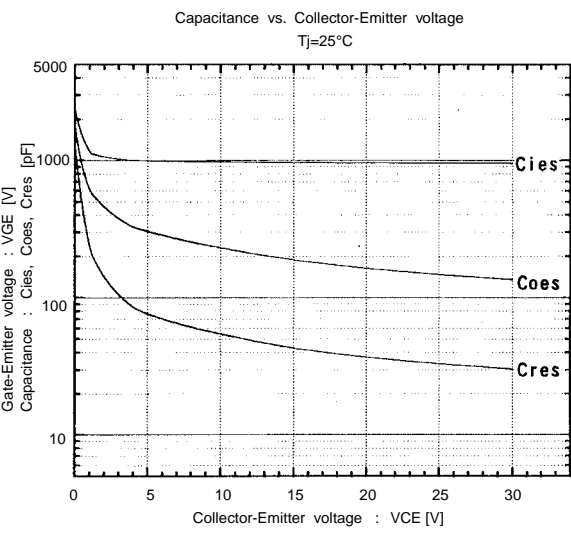
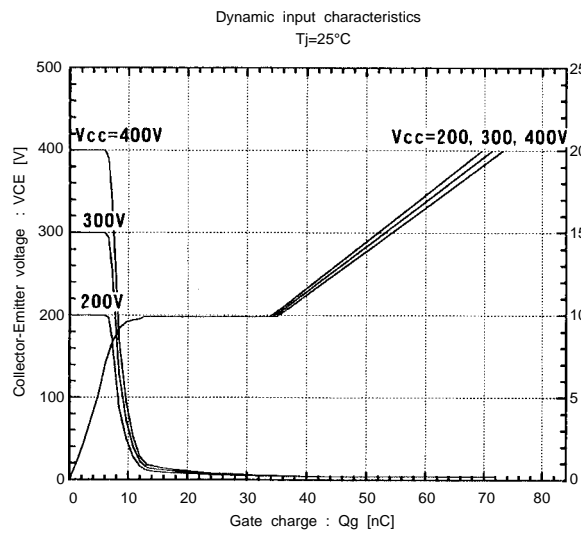
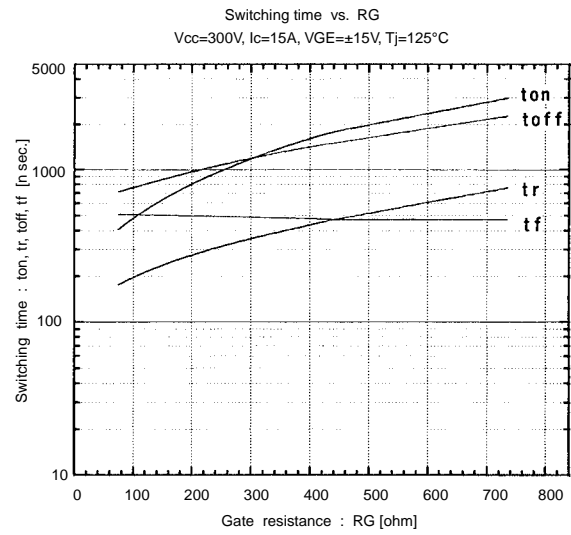
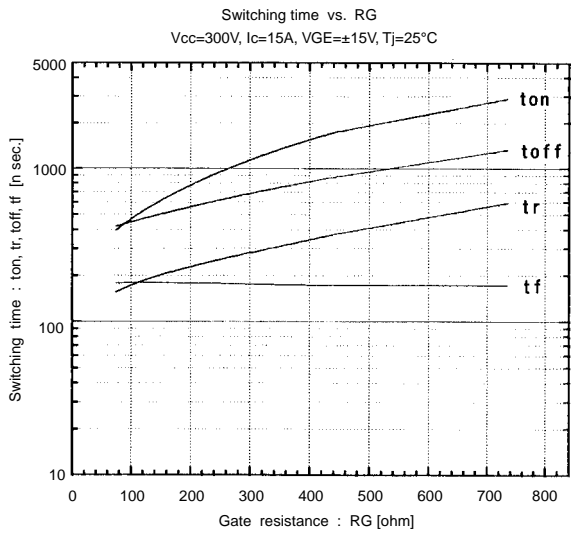
##### ● Thermal resistance characteristics

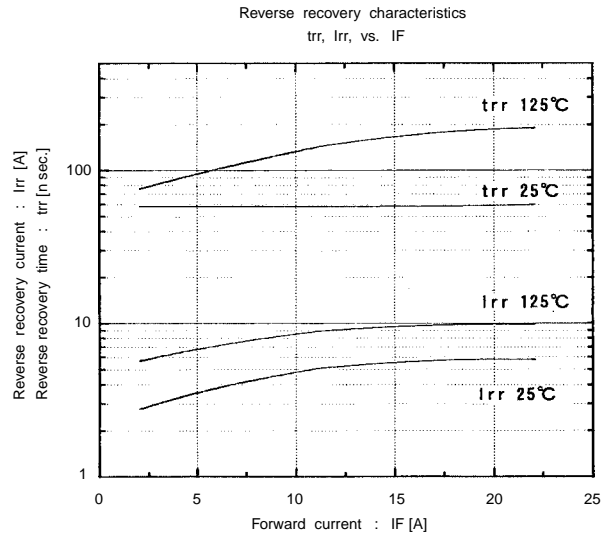
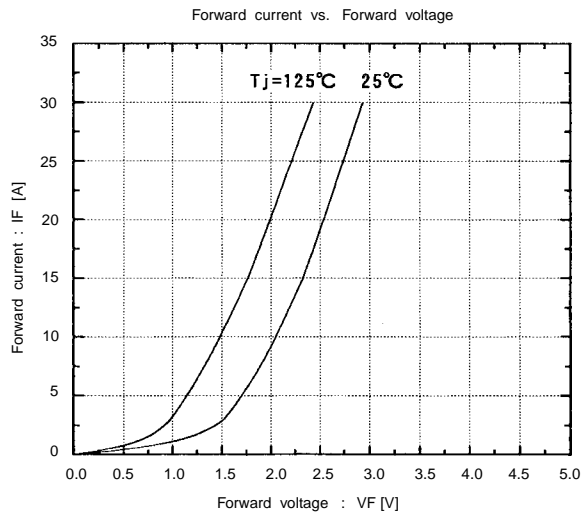
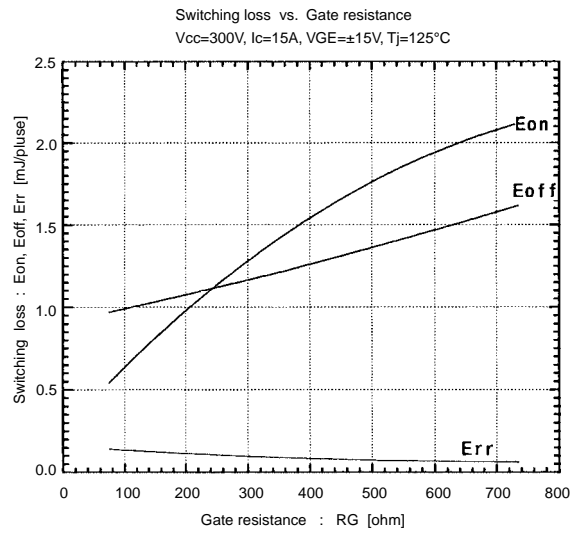
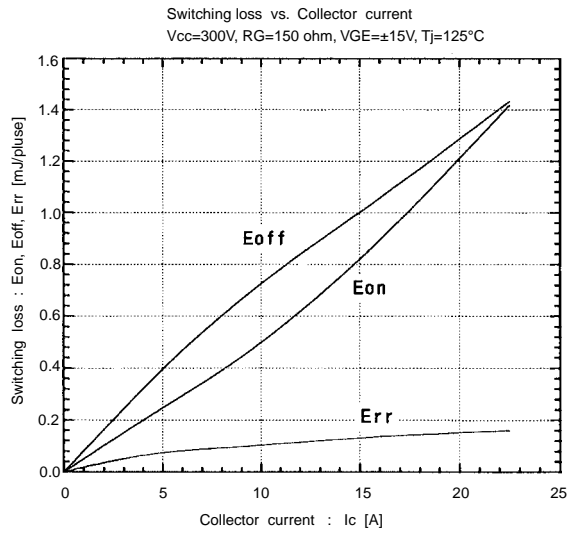
Item	Symbol	Characteristics			Conditions	Unit
		Min.	Typ.	Max.		
Thermal resistance	R <sub>th(j-c)</sub>	–	–	2.08	IGBT	°C/W
	R <sub>th(j-c)</sub>	–	–	3.0	Diode	°C/W
	R <sub>th(c-f)*2</sub>	–	0.06	–	the base to cooling fin	°C/W

\*2 : This is the value which is defined mounting on the additional cooling fin with thermal compound

Characteristics (Representative)







■ Outline Drawings, mm

